

## FEATURES

- Member of the Texas Instruments Widebus™ Family
- Optimized for 1.8-V Operation and Is 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- $I_{off}$  Supports Partial-Power-Down Mode Operation
- Sub-1-V Operable
- Max  $t_{pd}$  of 2.8 ns at 1.8 V
- Low Power Consumption, 20- $\mu$ A Max  $I_{cc}$
- $\pm 8$ -mA Output Drive at 1.8 V
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

## DESCRIPTION/ORDERING INFORMATION

This 16-bit edge-triggered D-type flip-flop is operational at 0.8-V to 2.7-V  $V_{CC}$ , but is designed specifically for 1.65-V to 1.95-V  $V_{CC}$  operation.

The SN74AUC16374 is particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers. It can be used as two 8-bit flip-flops or one 16-bit flip-flop. On the positive transition of the clock (CLK) input, the Q outputs of the flip-flop take on the logic levels set up at the data (D) inputs.

A buffered output-enable ( $\overline{OE}$ ) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

$\overline{OE}$  does not affect internal operations of the latch. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

## ORDERING INFORMATION

T <sub>A</sub>	PACKAGE <sup>(1)(2)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING
−40°C to 85°C	TSSOP – DGG	SN74AUC16374DGGR	AUC16374
	TVSOP – DGV	SN74AUC16374DGVR	MH374
	VFBGA – ZQL	SN74AUC16374ZQLR	MH374

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).

(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at [www.ti.com](http://www.ti.com).



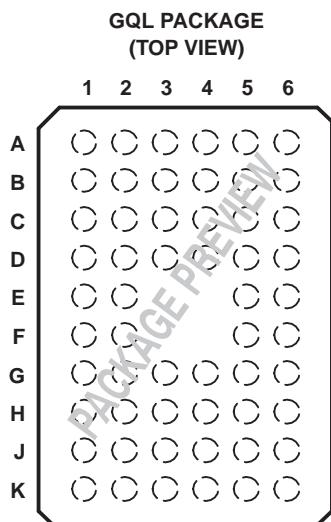
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Widebus is a trademark of Texas Instruments.

**DESCRIPTION/ORDERING INFORMATION (CONTINUED)**

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

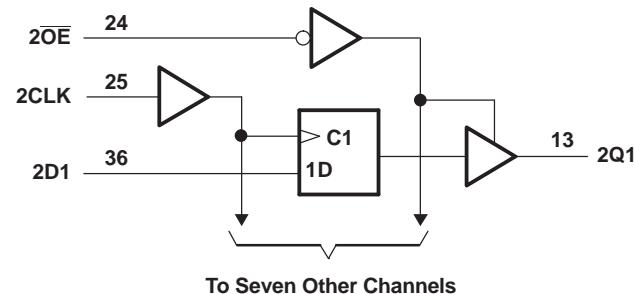
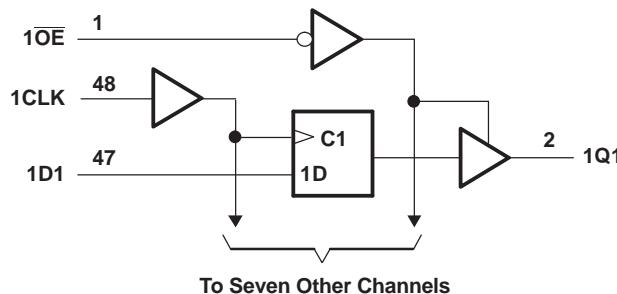
**TERMINAL ASSIGNMENTS<sup>(1)</sup>**

	1	2	3	4	5	6
<b>A</b>	1 $\overline{OE}$	NC	NC	NC	NC	1CLK
<b>B</b>	1Q2	1Q1	GND	GND	1D1	1D2
<b>C</b>	1Q4	1Q3	$V_{CC}$	$V_{CC}$	1D3	1D4
<b>D</b>	1Q6	1Q5	GND	GND	1D5	1D6
<b>E</b>	1Q8	1Q7			1D7	1D8
<b>F</b>	2Q1	2Q2			2D2	2D1
<b>G</b>	2Q3	2Q4	GND	GND	2D4	2D3
<b>H</b>	2Q5	2Q6	$V_{CC}$	$V_{CC}$	2D6	2D5
<b>J</b>	2Q7	2Q8	GND	GND	2D8	2D7
<b>K</b>	2 $\overline{OE}$	NC	NC	NC	NC	2CLK

(1) NC - No internal connection

**FUNCTION TABLE  
(EACH FLIP-FLOP)**

INPUTS		OUTPUT
$\overline{OE}$	CLK	Q
L	↑	H
L	↑	L
L	H or L	X
H	X	Z

**LOGIC DIAGRAM (POSITIVE LOGIC)**

Pin numbers shown are for the DGG and DGV packages.

### Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range	-0.5	3.6	V
V <sub>I</sub>	Input voltage range <sup>(2)</sup>	-0.5	3.6	V
V <sub>O</sub>	Voltage range applied to any output in the high-impedance or power-off state <sup>(2)</sup>	-0.5	3.6	V
V <sub>O</sub>	Output voltage range <sup>(2)</sup>	-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0	-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0	-50	mA
I <sub>O</sub>	Continuous output current		±20	mA
	Continuous current through V <sub>CC</sub> or GND		±100	mA
θ <sub>JA</sub>	Package thermal impedance <sup>(3)</sup>	DGG package	70	°C/W
		DGV package	58	
		GQL package	42	
T <sub>stg</sub>	Storage temperature range	-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The package thermal impedance is calculated in accordance with JESD 51-7.

### Recommended Operating Conditions<sup>(1)</sup>

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	0.8	2.7	V
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub>	V
		V <sub>CC</sub> = 1.1 V to 1.95 V	0.65 × V <sub>CC</sub>	
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	
V <sub>IL</sub>	Low-level input voltage	V <sub>CC</sub> = 0.8 V	0	V
		V <sub>CC</sub> = 1.1 V to 1.95 V	0.35 × V <sub>CC</sub>	
		V <sub>CC</sub> = 2.3 V to 2.7 V	0.7	
V <sub>I</sub>	Input voltage	0	3.6	V
V <sub>O</sub>	Output voltage	0	V <sub>CC</sub>	V
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 0.8 V	-0.7	mA
		V <sub>CC</sub> = 1.1 V	-3	
		V <sub>CC</sub> = 1.4 V	-5	
		V <sub>CC</sub> = 1.65 V	-8	
		V <sub>CC</sub> = 2.3 V	-9	
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 0.8 V	0.7	mA
		V <sub>CC</sub> = 1.1 V	3	
		V <sub>CC</sub> = 1.4 V	5	
		V <sub>CC</sub> = 1.65 V	8	
		V <sub>CC</sub> = 2.3 V	9	
Δt/Δv	Input transition rise or fall rate		20	ns/V
T <sub>A</sub>	Operating free-air temperature	-40	85	°C

(1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

SN74AUC16374

**16-BIT EDGE-TRIGGERED D-TYPE FLIP-FLOP  
WITH 3-STATE OUTPUTS**

SCES403E–JULY 2002–REVISED APRIL 2007

## Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP <sup>(1)</sup>	MAX	UNIT
V <sub>OH</sub>	I <sub>OH</sub> = -100 µA		0.8 V to 2.7 V	V <sub>CC</sub> – 0.1			V
	I <sub>OH</sub> = -0.7 mA		0.8 V		0.55		
	I <sub>OH</sub> = -3 mA		1.1 V		0.8		
	I <sub>OH</sub> = -5 mA		1.4 V		1		
	I <sub>OH</sub> = -8 mA		1.65 V		1.2		
	I <sub>OH</sub> = -9 mA		2.3 V		1.8		
V <sub>OL</sub>	I <sub>OL</sub> = 100 µA		0.8 V to 2.7 V		0.2		V
	I <sub>OL</sub> = 0.7 mA		0.8 V		0.25		
	I <sub>OL</sub> = 3 mA		1.1 V		0.3		
	I <sub>OL</sub> = 5 mA		1.4 V		0.4		
	I <sub>OL</sub> = 8 mA		1.65 V		0.45		
	I <sub>OL</sub> = 9 mA		2.3 V		0.6		
I <sub>I</sub>	All inputs	V <sub>I</sub> = V <sub>CC</sub> or GND	0 to 2.7 V		±5	µA	
I <sub>off</sub>		V <sub>I</sub> or V <sub>O</sub> = 2.7 V	0		±10	µA	
I <sub>OZ</sub>		V <sub>O</sub> = V <sub>CC</sub> or GND	2.7 V		±10	µA	
I <sub>CC</sub>		V <sub>I</sub> = V <sub>CC</sub> or GND, I <sub>O</sub> = 0	0.8 V to 2.7 V		20	µA	
C <sub>i</sub>		V <sub>I</sub> = V <sub>CC</sub> or GND	2.5 V		3	pF	
C <sub>o</sub>		V <sub>O</sub> = V <sub>CC</sub> or GND	2.5 V		5	pF	

(1) All typical values are at T<sub>A</sub> = 25°C.

## Timing Requirements

over recommended operating free-air temperature range (unless otherwise noted) (see [Figure 1](#))

		V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = 1.2 V ± 0.1 V		V <sub>CC</sub> = 1.5 V ± 0.1 V		V <sub>CC</sub> = 1.8 V ± 0.15 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		UNIT	
			TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>clock</sub>	Clock frequency	85		250		250		250		250		MHz
t <sub>w</sub>	Pulse duration, CLK high or low	5.9		1.9		1.9		1.9		1.9		ns
t <sub>su</sub>	Setup time, data before CLK↑	1.4		1.2		0.7		0.6		0.6		ns
t <sub>h</sub>	Hold time, data after CLK↑	0.1		0.4		0.4		0.4		0.4		ns

## Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see [Figure 1](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 0.8 V		V <sub>CC</sub> = 1.2 V ± 0.1 V		V <sub>CC</sub> = 1.5 V ± 0.1 V		V <sub>CC</sub> = 1.8 V ± 0.15 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		UNIT
			TYP	MIN	MAX	MIN	MAX	MIN	TYP	MAX	MIN	MAX	
f <sub>max</sub>			85	250		250		250		250		250	MHz
t <sub>pd</sub>	CLK	Q	7.3	1	4.5	0.8	2.9	0.7	1.5	2.8	0.7	2.2	ns
t <sub>en</sub>	OE	Q	7	1.2	5.3	0.8	3.6	0.8	1.5	2.9	0.7	2.2	ns
t <sub>dis</sub>	OE	Q	8.2	2	7.1	1	4.8	1.4	2.7	4.5	0.5	2.2	ns

## Operating Characteristics<sup>(1)</sup>

T<sub>A</sub> = 25°C

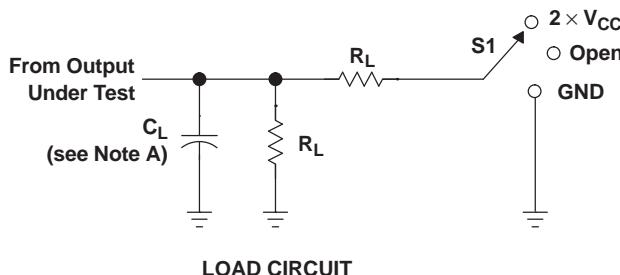
PARAMETER	TEST CONDITIONS	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = 1.2 V	V <sub>CC</sub> = 1.5 V	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V	UNIT	
		TYP	TYP	TYP	TYP	TYP		
C <sub>pd</sub> (each output) <sup>(2)</sup>	Power dissipation capacitance Outputs enabled, 1 output switching	1 f <sub>data</sub> = 5 MHz, 1 f <sub>clk</sub> = 10 MHz, 1 f <sub>out</sub> = 5 MHz, OĒ = GND, C <sub>L</sub> = 0 pF	24	24	24.1	26.2	31.2	pF
C <sub>pd(Z)</sub>	Power dissipation capacitance Outputs disabled, 1 clock and 1 data switching	1 f <sub>data</sub> = 5 MHz, 1 f <sub>clk</sub> = 10 MHz, f <sub>out</sub> = not switching, OĒ = V <sub>CC</sub> , C <sub>L</sub> = 0 pF	7.5	7.5	8	9.4	13.2	pF
C <sub>pd</sub> (each clock) <sup>(3)</sup>	Power dissipation capacitance Outputs disabled, clock only switching	1 f <sub>data</sub> = 0 MHz, 1 f <sub>clk</sub> = 10 MHz, f <sub>out</sub> = not switching, OĒ = V <sub>CC</sub> , C <sub>L</sub> = 0 pF	13.8	13.8	14	14.7	17.5	pF

(1) Total device C<sub>pd</sub> for multiple (n) outputs switching and (y) clocks inputs switching = {n \* C<sub>pd</sub> (each output)} + {y \* C<sub>pd</sub> (each clock)}

(2) C<sub>pd</sub> (each output) is the C<sub>pd</sub> for each data bit (input and output circuitry) as it operates at 5 MHz (Note: the clock is operating at 10 MHz in this test, but its I<sub>CC</sub> component has been subtracted out).

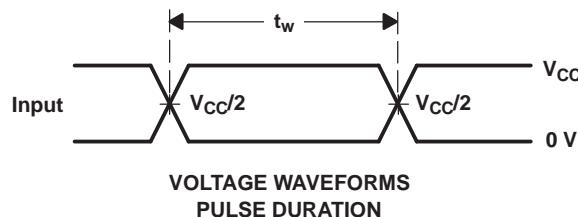
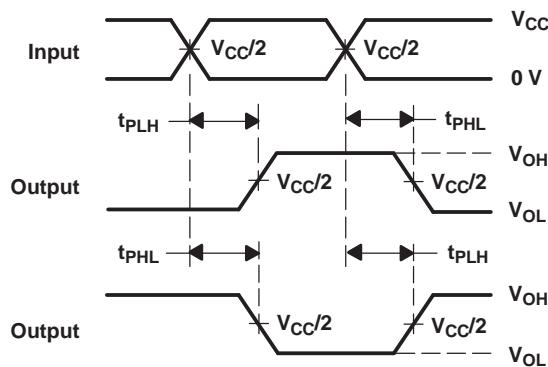
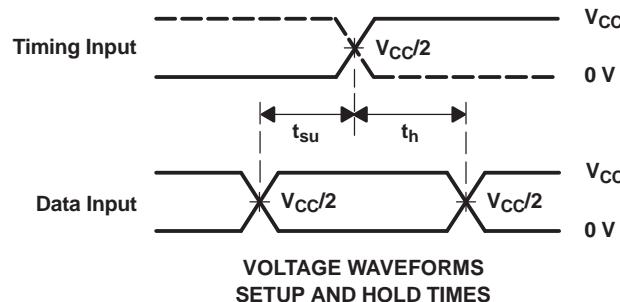
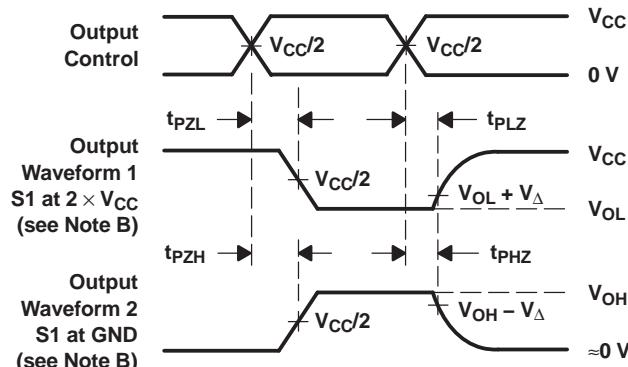
(3) C<sub>pd</sub> (each clock) is the C<sub>pd</sub> for the clock circuitry only as it operates at 10 MHz.

## PARAMETER MEASUREMENT INFORMATION



TEST	S1
$t_{PLH}/t_{PHL}$	Open
$t_{PLZ}/t_{PZL}$	$2 \times V_{CC}$
$t_{PHZ}/t_{PZH}$	GND

$V_{CC}$	$C_L$	$R_L$	$V_\Delta$
0.8 V	15 pF	2 kΩ	0.1 V
$1.2 V \pm 0.1 V$	15 pF	2 kΩ	0.1 V
$1.5 V \pm 0.1 V$	15 pF	2 kΩ	0.1 V
$1.8 V \pm 0.15 V$	30 pF	1 kΩ	0.15 V
$2.5 V \pm 0.2 V$	30 pF	500 Ω	0.15 V

VOLTAGE WAVEFORMS  
PULSE DURATIONVOLTAGE WAVEFORMS  
PROPAGATION DELAY TIMES  
INVERTING AND NONINVERTING OUTPUTSVOLTAGE WAVEFORMS  
SETUP AND HOLD TIMESVOLTAGE WAVEFORMS  
ENABLE AND DISABLE TIMES  
LOW- AND HIGH-LEVEL ENABLING

- NOTES:
- A.  $C_L$  includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq 10$  MHz,  $Z_O = 50 \Omega$ , slew rate  $\geq 1$  V/ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
  - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
74AUC16374DGGRG4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AUC16374	<b>Samples</b>
SN74AUC16374DGGR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AUC16374	<b>Samples</b>
SN74AUC16374DGVR	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MH374	<b>Samples</b>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and



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## PACKAGE OPTION ADDENDUM

10-Jun-2014

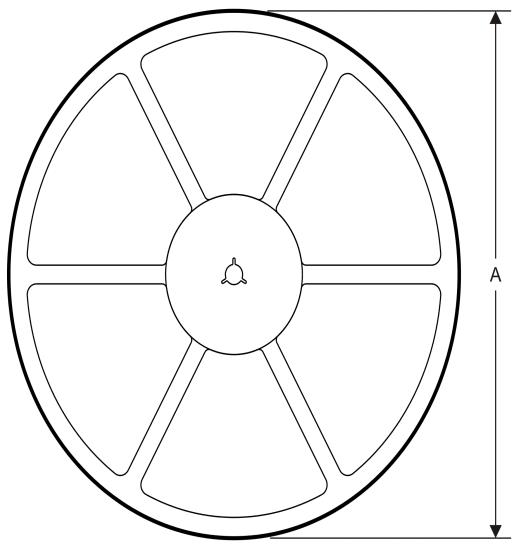
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continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

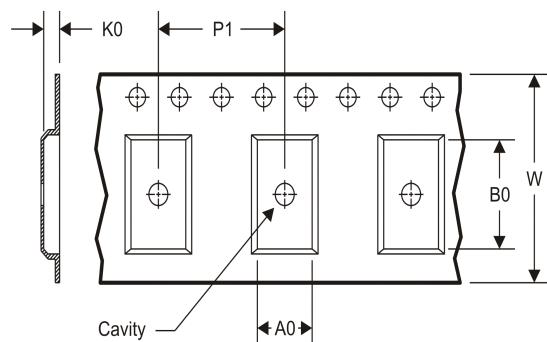
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## TAPE AND REEL INFORMATION

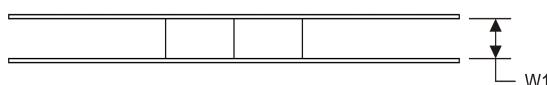
### REEL DIMENSIONS



### TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

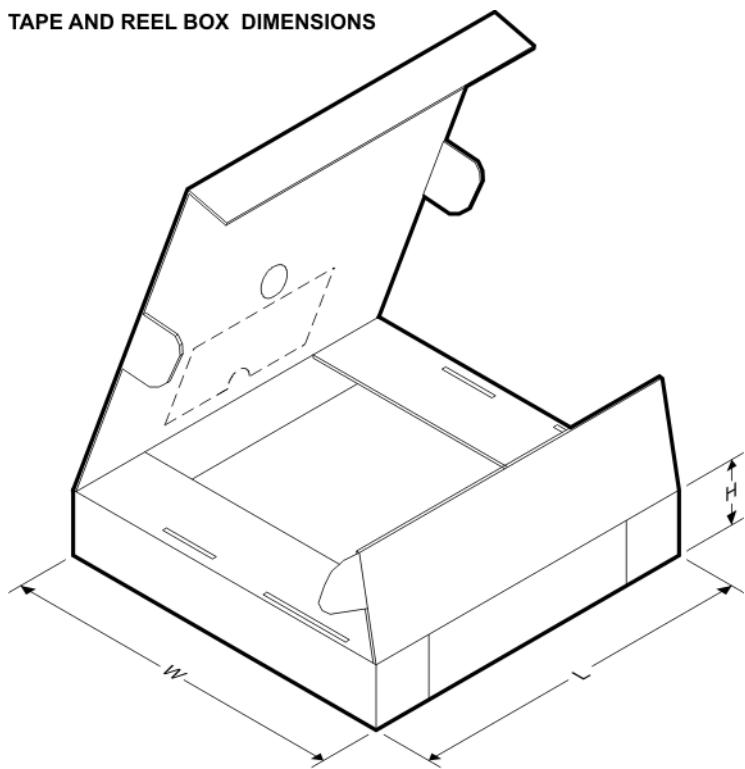


### TAPE AND REEL INFORMATION

\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUC16374DGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	15.8	1.8	12.0	24.0	Q1
SN74AUC16374DGVR	TVSOP	DGV	48	2000	330.0	16.4	7.1	10.2	1.6	12.0	16.0	Q1

## TAPE AND REEL BOX DIMENSIONS



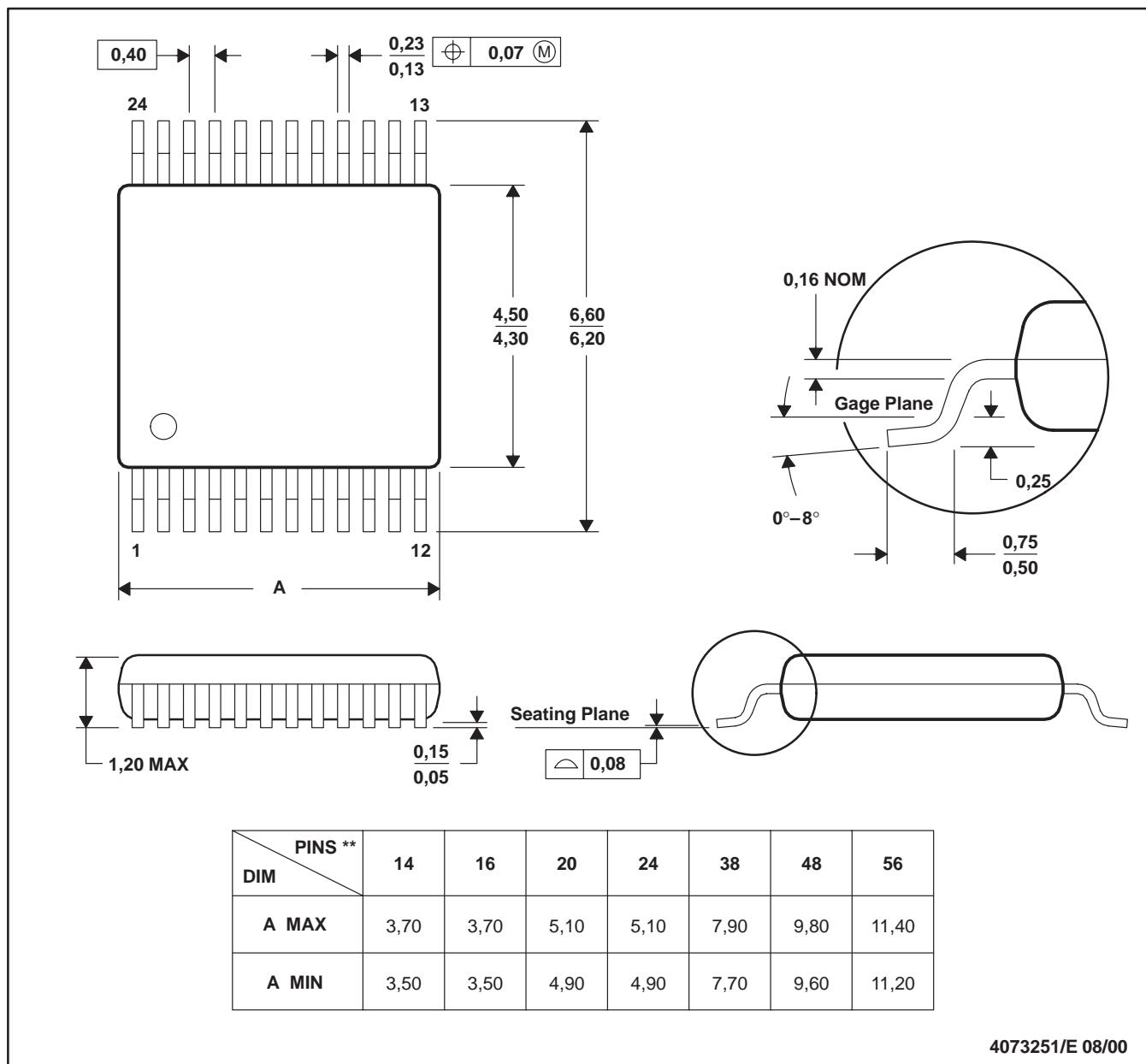
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUC16374DGGR	TSSOP	DGG	48	2000	367.0	367.0	45.0
SN74AUC16374DGVR	TVSOP	DGV	48	2000	367.0	367.0	38.0

## DGV (R-PDSO-G\*\*)

## PLASTIC SMALL-OUTLINE

24 PINS SHOWN

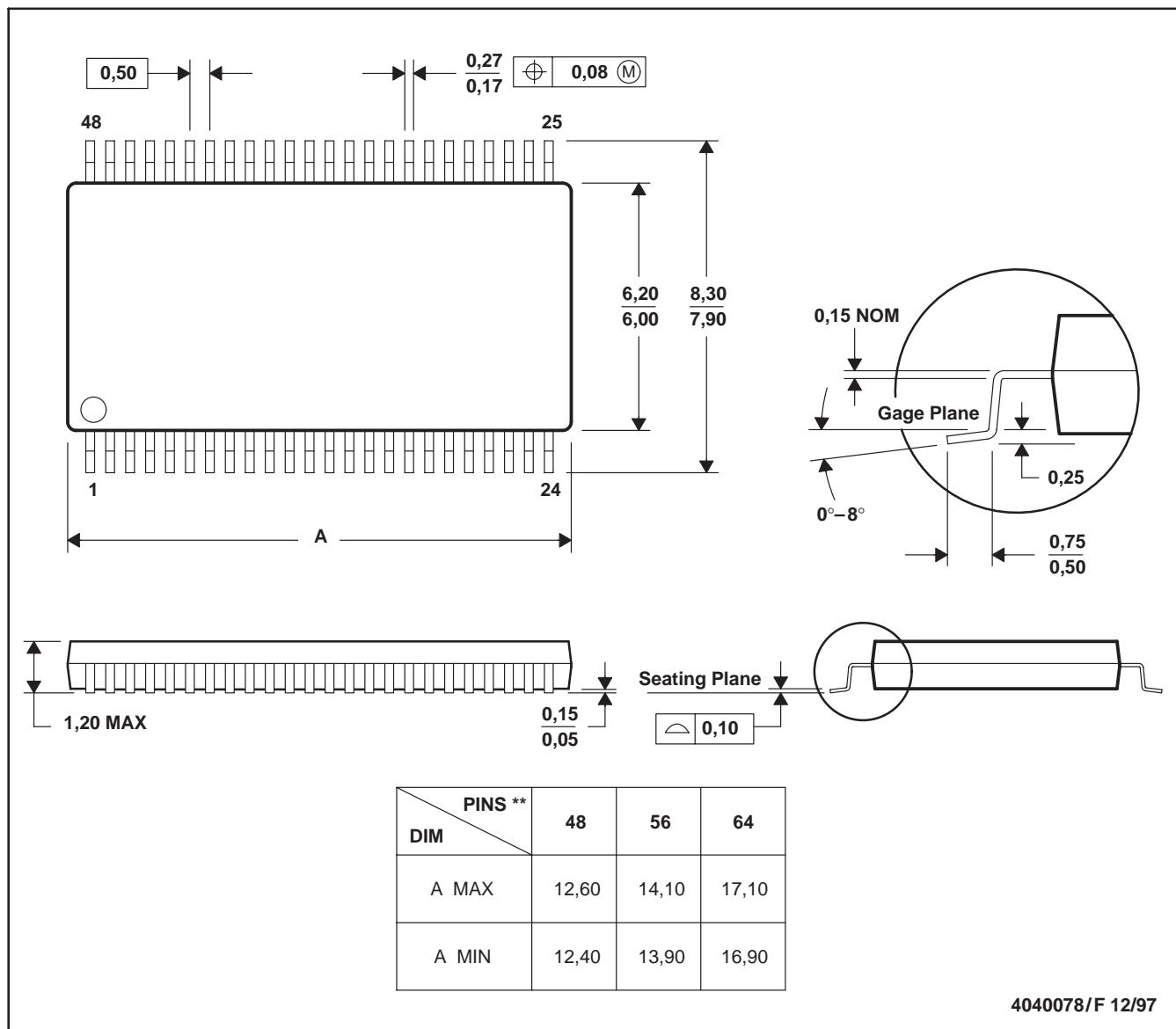


- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
  - D. Falls within JEDEC: 24/48 Pins – MO-153  
14/16/20/56 Pins – MO-194

## DGG (R-PDSO-G\*\*)

## PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold protrusion not to exceed 0,15.  
 D. Falls within JEDEC MO-153

## IMPORTANT NOTICE

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